A Product Line of
Diodes Incorporated

PI3CSW12

High-Speed I3C 1:2 Multiplexer/DeMultiplexer Switch with Signal Enable

Features

- V_{DD} Operation at 2.5V and 3.3V
- $V_{I/O}$ Accepts Signals up to 5.5V
- 1.8-V Compatible Control-Pin Inputs
- Low-Power Mode When $\overline{OE}$ Is Disabled (2µA)
- r_{ON} = 6Ω Maximum
- Δr_{ON} = 0.2Ω Typical
- Cio(on) = 4pF Typical
- Support Over Voltage Protection
- Low Power Consumption (50µA Maximum)
- ESD Performance
  - IO Pins
  - 12KV HBM
  - 1KV CDM
  - +/-8KV contact Discharge (IEC61000-4-2)
  - VDD, GND, S, $\overline{OE}$ Pins
  - 4KV HBM
  - 1KV CDM
- High Bandwidth (1.6GHz Typical)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
  https://www.diodes.com/quality/product-definitions/
- Packaging (Pb-free & Green):
  - 10-contact, UQFN (ZUA10)

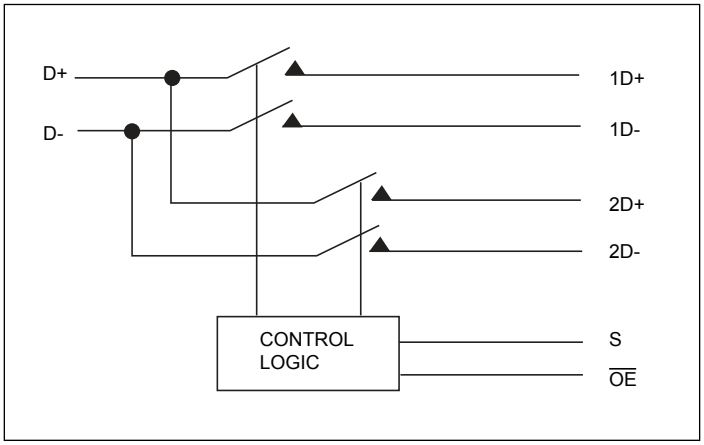
Applications

- Routes Signals for I3C
- Mobile Industry Processor Interface (MIPI) Signal Routing

Description

The PI3CSW12 is a high-bandwidth switch specially designed for the switching of high-speed I3C signals in communication and server applications, such as servers, workstations, and notebooks with hubs or controllers with limited I3C I/Os. The wide bandwidth (1.6GHz) of this switch allows signals to pass with minimum edge and phase distortion. The device multiplexes differential outputs from a I3C host device to one of two corresponding outputs. The switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. It is designed for low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed I3C (up to 30Mbps).

Block Diagram

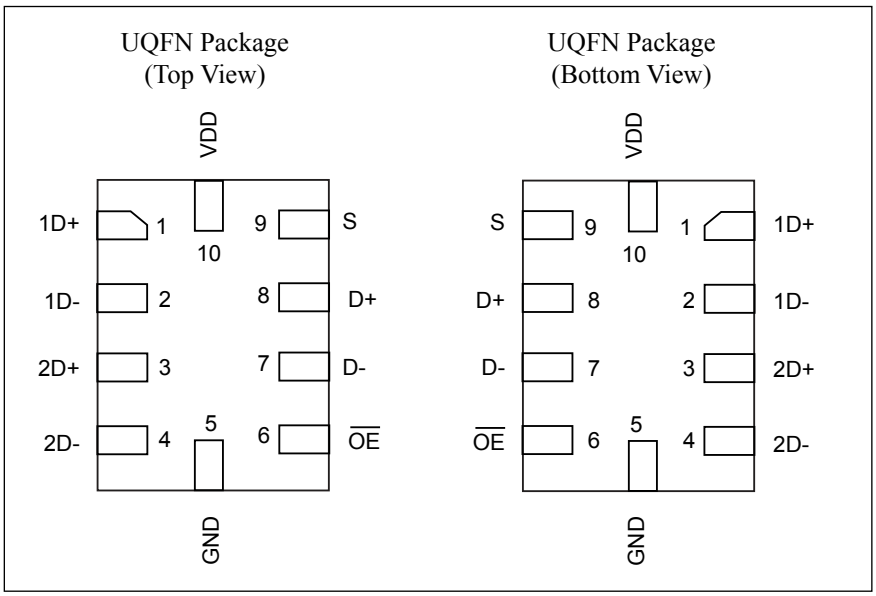


Truth Table

S	$\overline{OE}$	Function
X	H	Disconnect
L	L	D = 1D
H	L	D = 2D

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Configuration



Pin Description

Name	Description
$\overline{OE}$	Active LOW, Output enable
S	Select input
D	COM port
nD	I/O for I3C data path (port 1 and port 2)

Absolute Maximum Ratings(1)

Over operating free-air temperature range (unless otherwise noted)

V_{DD} Supply Voltage Range	–0.5V to 4.6V
V_{IN} Control Input Voltage Range(2, 3)	–0.5V to 5.5V
$V_{I/O}$ Switch I/O Voltage Range(2, 3, 4)	–0.5V to 5.5V
I_{IK} Control Input Clamp Current (V_{IN} < 0)	–50mA
$I_{I/OK}$ I/O Port Clamp Current ($V_{I/O}$ < 0)	–50mA
$I_{I/O}$ ON-state Switch Current(5)	±120mA
Continuous Current through V_{DD} or GND	±100mA
θ_{JA} Package Thermal Impedance	
TLLGA Package	48.7°C/W
TDFN Package	243°C/W
T_{stg} Storage Temperature Range	–65 to 150°C
Tj Junction Temperature	125°C

Notes:

1. Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. All voltages are with respect to ground, unless otherwise specified.
3. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
4. VI and VO are used to denote specific conditions for VI/O.
5. II and IO are used to denote specific conditions for II/O.
6. The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions(1)

Symbol	Description	Parameter	Min.	Max.	Unit
V_{DD}	Supply voltage		2.3	3.6	V
V_{IH}	High-level control input voltage	V_{DD} = 2.3V to 2.7V	1.3	-	
		V_{DD} = 2.7V to 3.6V	1.4	-	
V_{IL}	Low-level control input voltage	V_{DD} = 2.3V to 2.7V		0.6	
		V_{DD} = 2.7V to 3.6V		0.6	
$V_{I/O}$	Data input/output voltage		0	4.6	
T_A	Operating free-air temperature		–40	85	°C

Note:

1. All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation.

Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted)

Parameter		Testing Conditions		Min.	Typ.	Max.	Unit
V_{IK}		V_{DD} = 3.6V, 2.7V, I_I = –18 mA				–1.2	V
I_{IN}	Control Inputs	V_{DD} = 3.6V, 2.7V, 0V, V_{IN} = 0V to 3.6V				±1	μA
I_{OZ}(3)		V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} or GND, V_O = 0V to 3.6V, V_I = 0V, Switch OFF				±1	
$I_{(OFF)}$		V_{DD} = 0V	$V_{I/O}$ = 0V to 3.6V			±2	
			$V_{I/O}$ = 0 to 2.7V			±1	
I_{CC}		V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} or GND, $I_{I/O}$ = 0 V, Switch ON or OFF			25	50	
I_{CC} (low power mode)		V_{DD} = 3.6V, 2.7V, V_{IN} = V_{DD} or GND, Switch disabled, ($\overline{OE}$ in high state)				4	
DI_{CC}(4)	Control Inputs		V_{DD} = 2.7V, S sweeps from 1.4V to 3.3V, OE/ = 0V			15	
			V_{DD} = 2.7V, OE/ sweeps from 1.4V to 3.3V, S = 0V			0.75	
C_{IN}	Control Inputs	V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V or 0V			1	2	pF
$C_{io(OFF)}$		V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V or 0V, Switch OFF			2	3	
$C_{io(ON)}$		V_{DD} = 3.3V, 2.5V, V_{IN} = 3.3V or 0V, Switch ON			4		
r_{ON}(5)		V_{DD} = 3V, 2.3V	V_I = 0V, I_O = 30mA			4	Ω
			V_I = 2.4V, I_O = –15mA			6	
Dr_{ON}(6)		V_{DD} = 3V, 2.3V	V_I = 0V, I_O = 30mA		0.2		
			V_I = 1.7V, I_O = –15mA		0.2		
$r_{ON(flat)}$		V_{DD} = 3V, 2.3V	V_I = 0V, I_O = 30mA		1		
			V_I = 1.7V, I_O = –15mA		1		
V_{pass}		V_{DD} = 2.5 - 3.3V	V_{IN} > 3.8V, I_O = 10uA	2.8	3.8	4.2	V

Notes:

1. V_{IN} and I_{IN} refer to control inputs. VI, VO, II, and IO refer to data pins.
2. All typical values are at V_{DD} = 3.3 V (unless otherwise noted), T_A = 25°C.
3. For I/O ports, the parameter IOZ includes the input leakage current.
4. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{DD} or GND.
5. Measured by the voltage drop between the input and output terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two terminals.
6. Dron is delta Ron between channels

Dynamic Electrical Characteristics

Over operating range, T_A = –40°C to 85°C, V_{DD} = 3.3 V ± 10%, GND = 0V

Symbol	Parameter	Test Conditions	Typ.(1)	Unit
X_{TALK}	Crosstalk	R_L = 50Ω, f = 250 MHz	–40	dB
		R_L = 50Ω, f = 50 MHz	–55	
O_{IRR}	OFF isolation	R_L = 50Ω, f = 250 MHz	–41	
BW	Bandwidth (–3 dB)	R_L = 50Ω	1.6	GHz

Note:
1. For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.

Switching Characteristics

Over operating range, T_A = –40°C to 85°C, V_{DD} = 3.3 V ± 10%, GND = 0V

Symbol	Parameter		Min.	Typ.(1)	Max.	Unit
t_{pd}	Propagation Delay (2,3)			0.25		ns
t_{ON}	Line enable time	S to D, nD			125	
		$\overline{OE}$ to D, nD			100	
t_{OFF}	Line disable time	S to D, nD			12	
		$\overline{OE}$ to D, nD			12	
$t_{SK(O)}$	Output skew between center port to any other port(2)			0.1	0.2	
$t_{SK(P)}$	Skew between opposite transitions of the same output (tPHL – tPLH)(2)			0.1	0.2	
t_{VPASS}	OVP response time			53		ns

Notes:
1. For Max or Min conditions, use the appropriate value specified under Electrical Characteristics for the applicable device type.
2. Specified by design
3. The switch contributes no propagation delay other than the RC delay of the on resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 10-pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.

Application Information

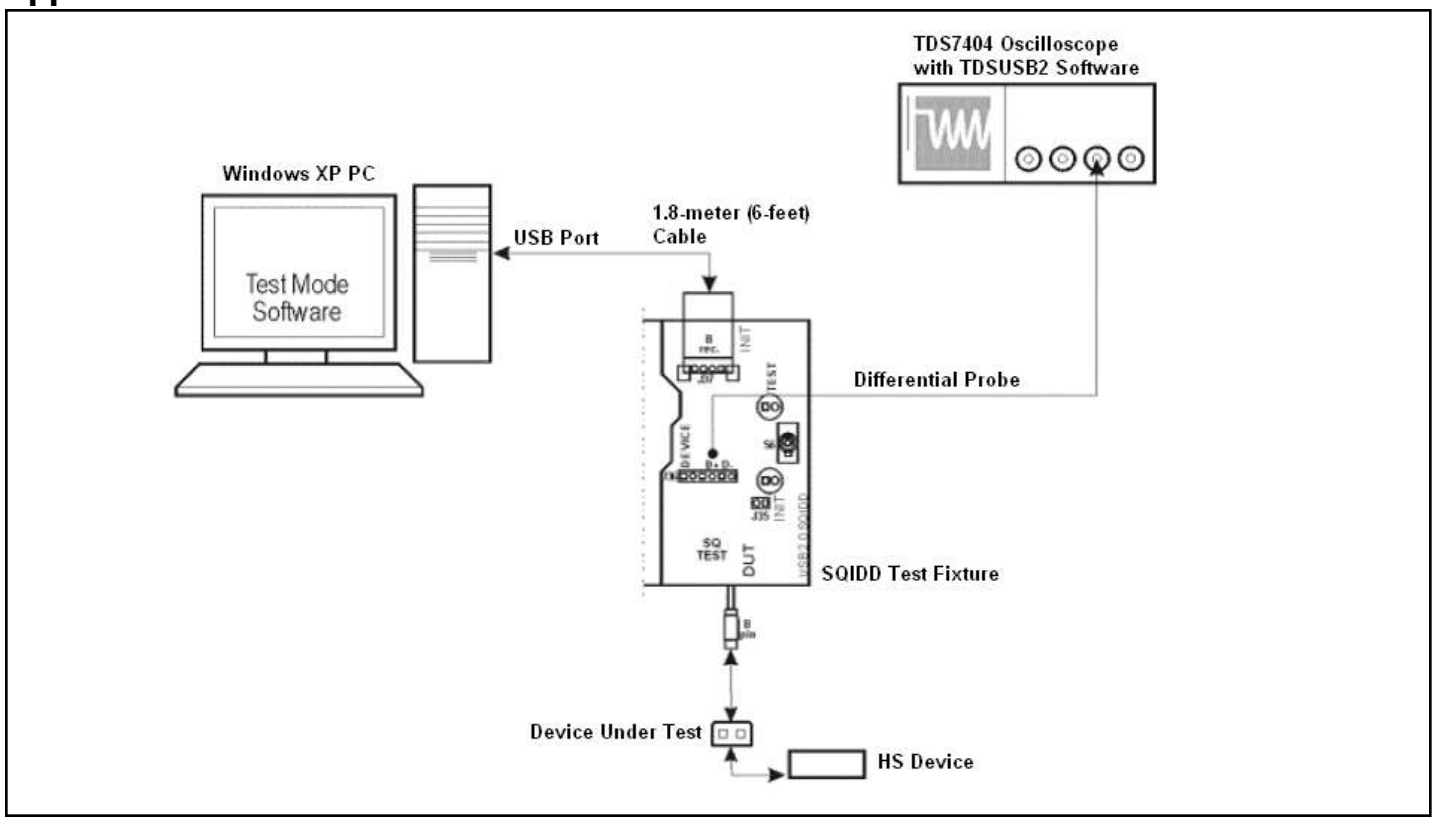
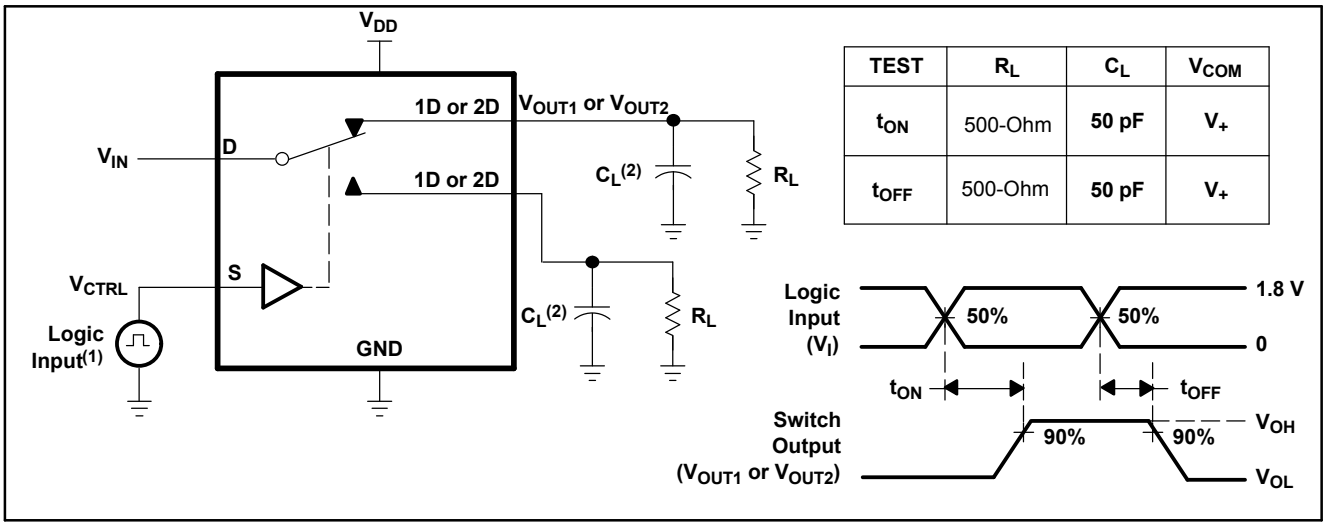


Figure 1: HS Eye Test Setup

Parameter Measurement Information



TEST	R_L	C_L	V_{COM}
t_{ON}	500-Ohm	50 pF	V_+
t_{OFF}	500-Ohm	50 pF	V_+

(1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50-Ohm, t_r < 5 ns, t_f < 5 ns.
(2) C_L includes probe and jig capacitance.

Figure 2. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

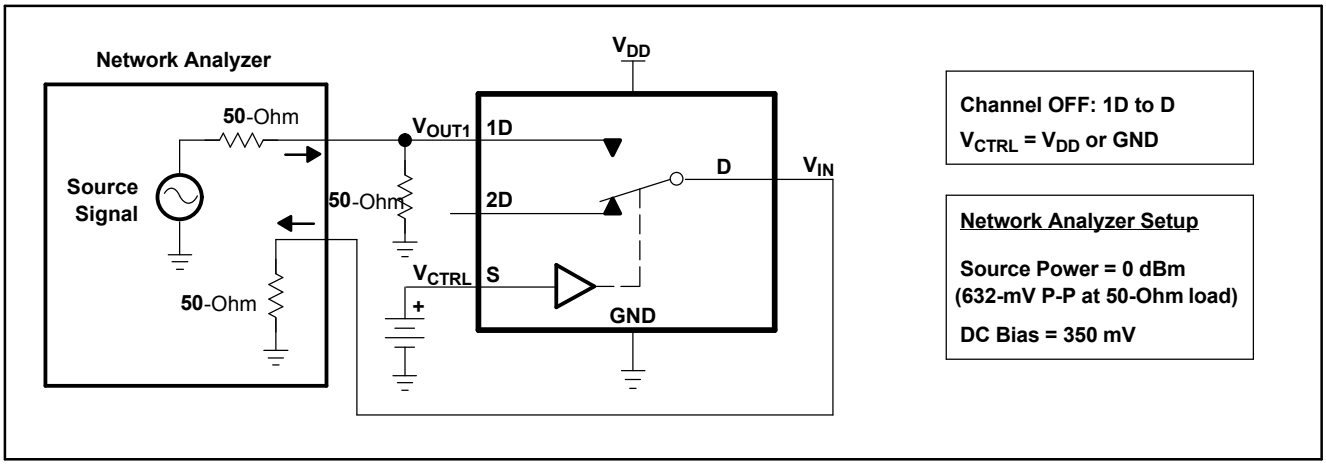


Figure 3. OFF Isolation (O_{ISO})

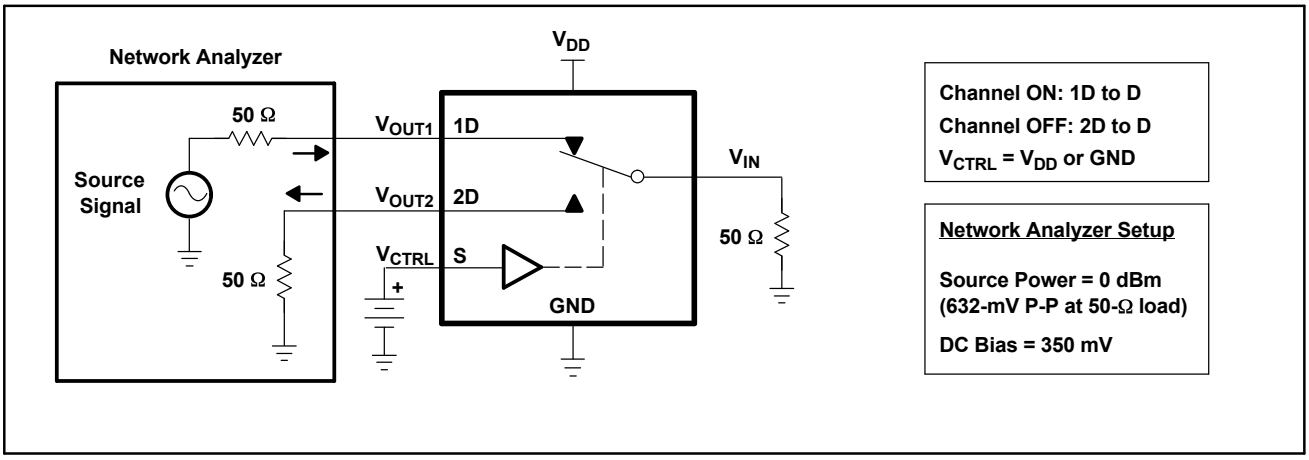


Figure 4. Crosstalk (X_{TALK})

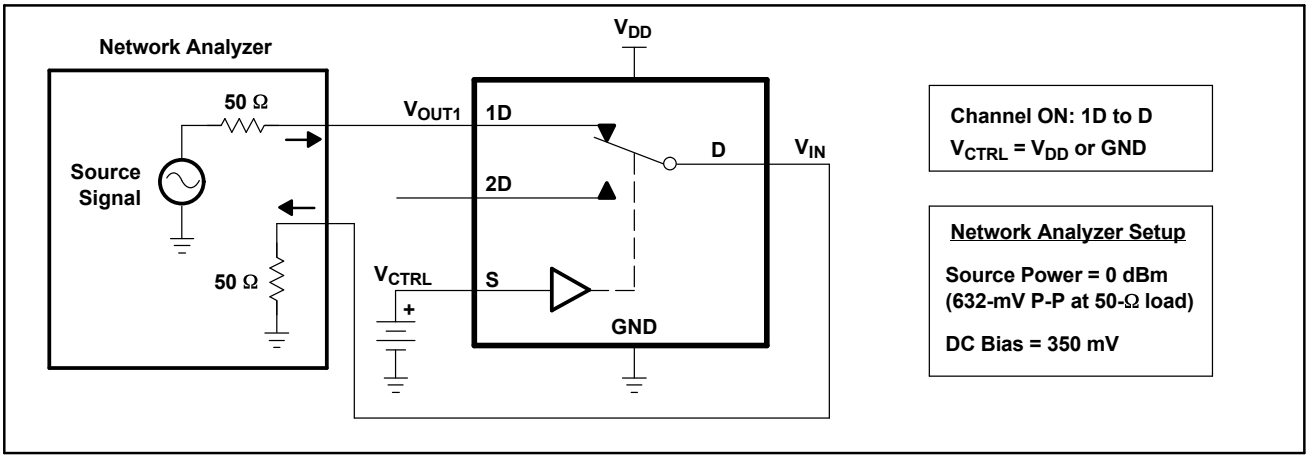


Figure 5. Bandwidth (BW)

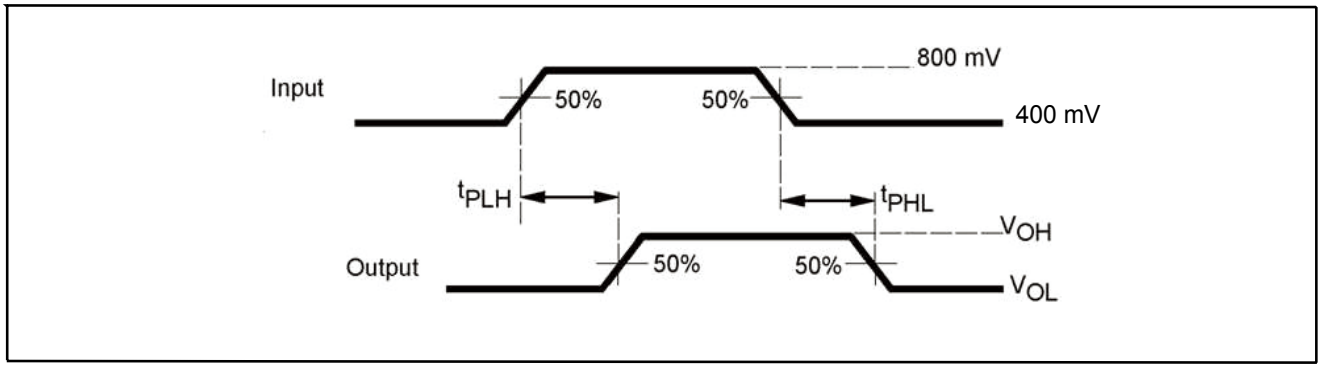


Figure 6. Propagation Delay

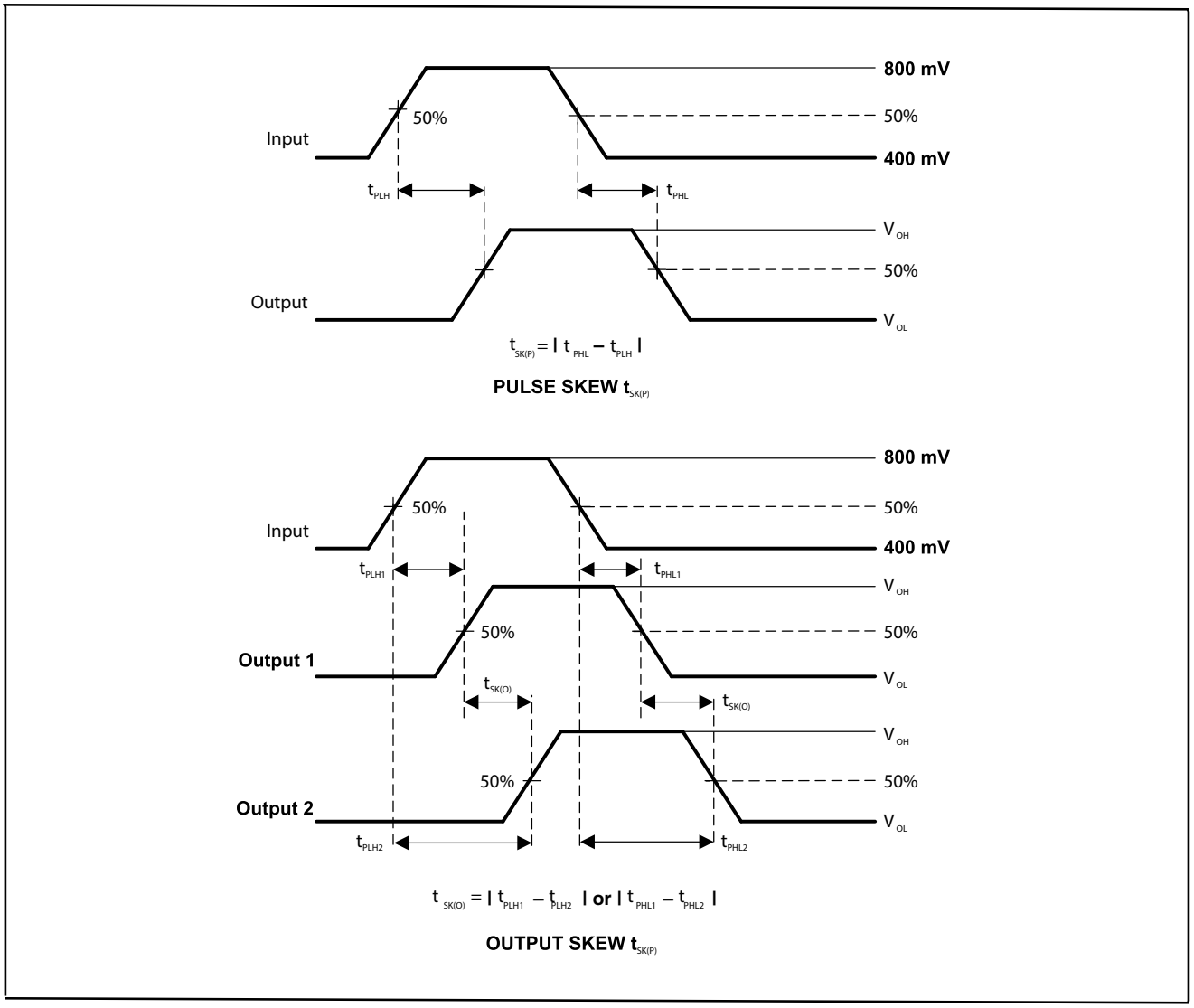


Figure 7. Skew Test

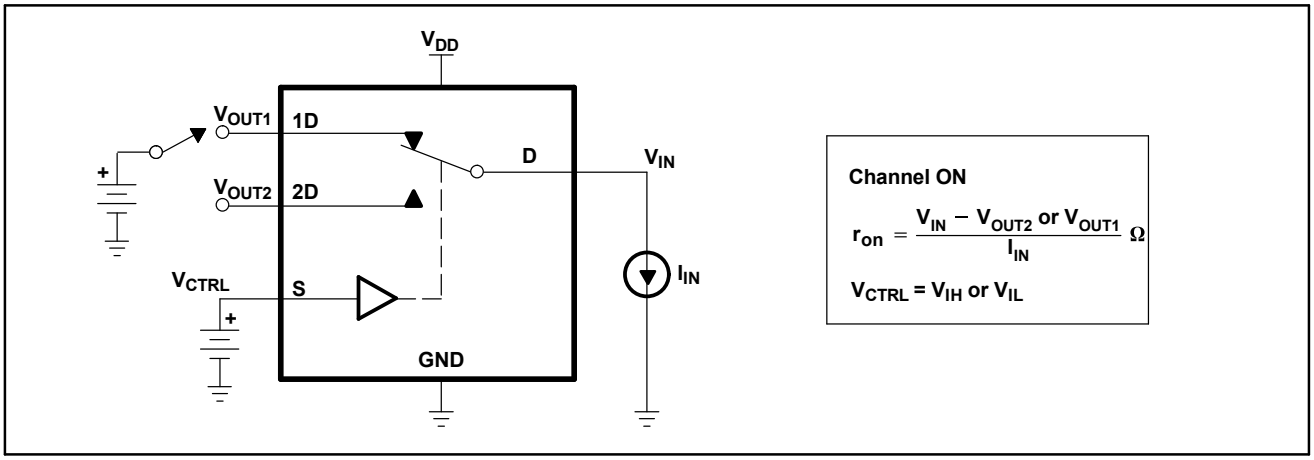


Figure 8. ON-State Resistance (r_{on})

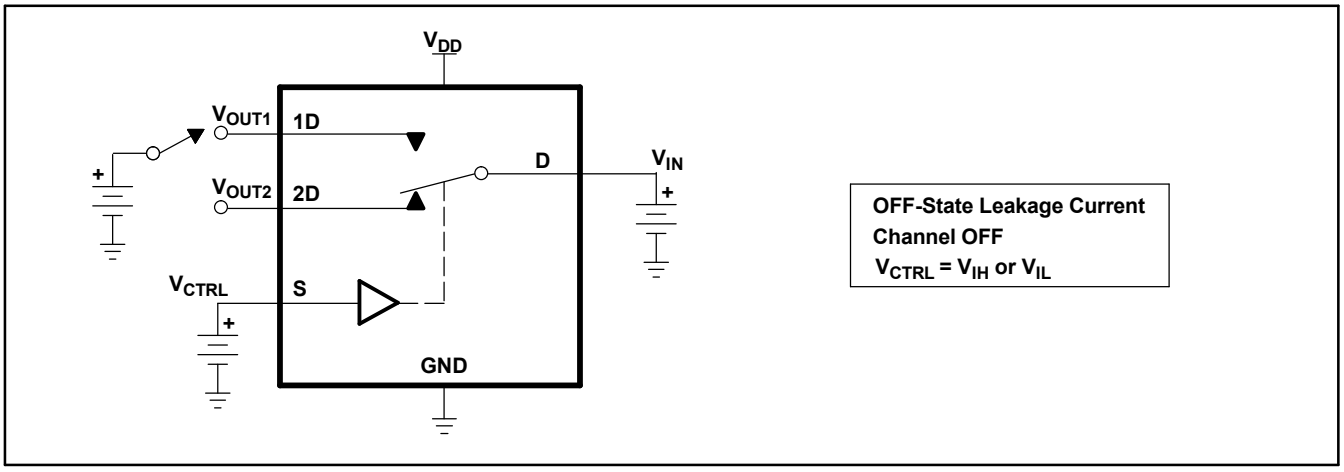


Figure 9. OFF-State Leakage Current

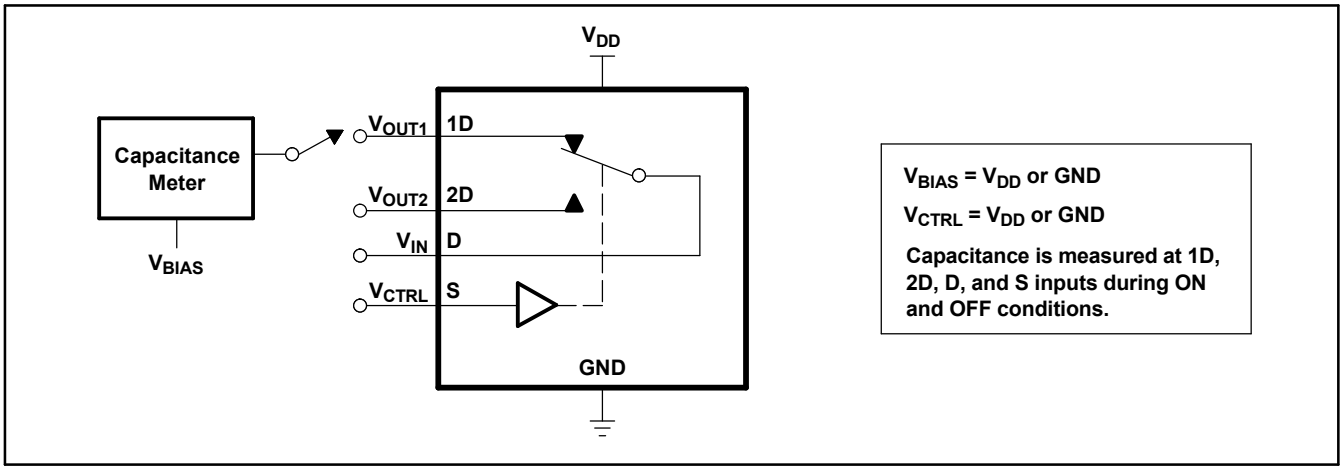
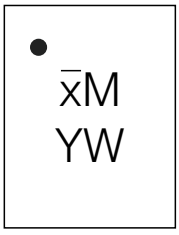


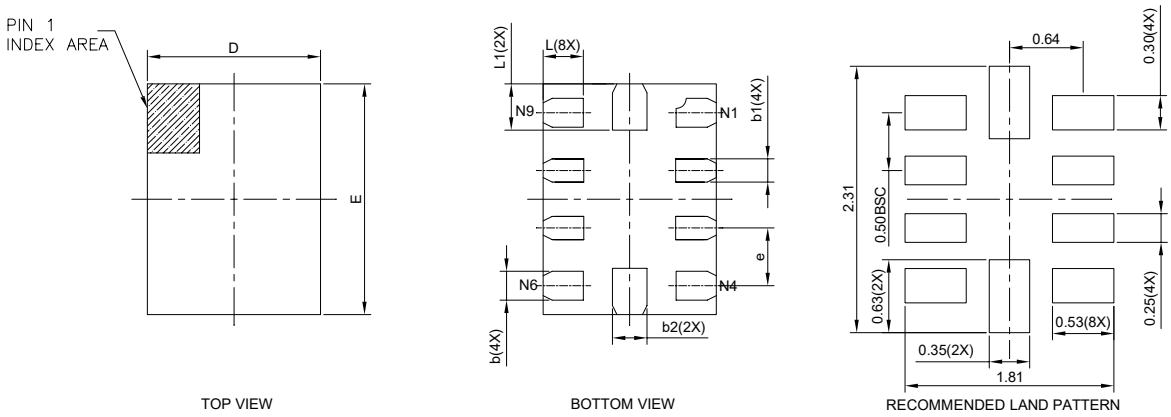
Figure 10. Capacitance

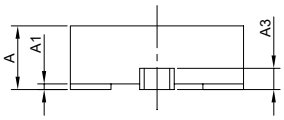
Part Marking



xM: PI3CSW12ZUAE
Y: Date Code (Year)
W: Date Code (Workweek)

Packaging Mechanical: 10-UQFN (ZUA)





PKG DIMENSIONS			
SYMBOL	MIM	NOM	MAX
A	0.50	---	0.65
A1	0.00	0.02	0.05
A3		0.15 REF	
D	1.45	1.50	1.55
E	1.95	2.00	2.05
b	0.20	0.25	0.30
b1	0.15	0.20	0.25
b2	0.25	0.30	0.35
e		0.50 BSC	
L	0.25	0.35	0.45
L1	0.30	0.40	0.50

Notes:
1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. Ref: JEDEC MO-288B.
3. RECOMMENDED LAND PATTERN IS FOR REFERENCE ONLY.

DATE: 07/13/20

DESCRIPTION: 10-Pin, UQFN, 1.5X2.0 (U-QFN1520-10)

PACKAGE CODE: ZUA(ZUA10)

DOCUMENT CONTROL#: PD-2220 **REVISION: A**

For latest package info.
please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Number	Package Code	Package Description
PI3CSW12ZUAEX	ZUA	10-Pin, 1.5x2.0 (UQFN) (U-QFN 1520-10)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
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3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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